

### **isc** Silicon NPN Power Transistor

## KTC4370

### DESCRIPTION

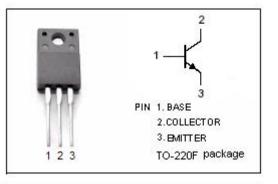
- High Collector-Emitter Breakdown Voltage V<sub>CEO</sub>= 160V(Min)
- Complement to Type KTA1659
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

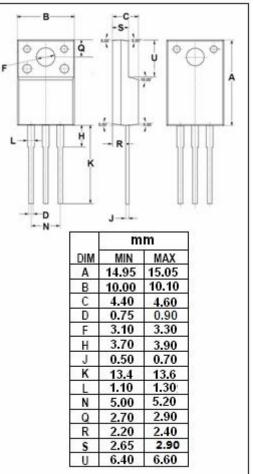
### **APPLICATIONS**

· Designed for high voltage applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER VAL		UNIT		
V <sub>CBO</sub>	Collector-Base Voltage 160		V		
V <sub>CEO</sub>	Collector-Emitter Voltage 160		V		
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V		
I <sub>C(DC)</sub>	Collector Current(DC)	1.5			
I <sub>B(DC)</sub>	Base Current	0.15	A		
Pc	Collector Power Dissipation @Tc=25°C	20	W		
TJ	Junction Temperature	150	°C		
T <sub>stg</sub>	Storage Temperature	-55~150	°C		







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### **ELECTRICAL CHARACTERISTICS**

#### Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; I <sub>B</sub> = 0	160			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 500mA; I <sub>B</sub> = 50mA			1.5	V
$V_{\text{BE(on)}}$	Base-Emitter On Voltage	I <sub>C</sub> = 500mA; V <sub>CE</sub> = 5V			1.0	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 160V ; I <sub>E</sub> = 0			1.0	μA
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> =0			1.0	μA
h <sub>FE</sub>	DC Current Gain	Ic= 100mA ; Vce= 5V	70		240	

### h<sub>FE</sub> Classifications

0	Y		
70-140	120-240		

### NOTICE:

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